Influence of electronic structure parameters on the electrical transport and magnetic properties of $Y_{2-x}Bi_xIr_2O_7$ pyrochlore iridates

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We report the systematic study of structural, magnetic and electrical transport properties of $Y_{2-x}Bi_xIr_2O_7$ ($x = 0.0, 0.1, 0.2, 0.3$) pyrochlore iridates. The chemical doping enhances electrical conductivity and antiferromagnetic correlation substantially. The replacement of non-magnetic $Y^{3+}$ ion with non-magnetic $Bi^{3+}$ in $Y_2Ir_2O_7$ tends to reduce the octahedral distortion thus enhancing the antiferromagnetic correlation. Raman spectroscopy shows that the $Ir-O$ bond contract slightly and the $R-O'$ bond turn longer as disorder and phonon oscillation are reduced with $Bi$ doping, leading to wider $t_{2g}$ bands, which enhances the electrical conductivity. Additionally, the enhancement in electrical conductivity with $Bi^{3+}$ doping is attributed to the hybridization between the $Y^{3+}(4p)/Bi^{3+}(6s/6p)$ orbital with $Ir^{4+}(5d)$ orbital. On the other hand, enhancement in $Ir-O-Ir$ bond angle against $Bi$ doping make the system more conducting and enhances the antiferromagnetic correlation than parent compound.

I. INTRODUCTION

In recent years, 5d iridates have proved to be a fertile ground of new physics driven by the interplay between the onsite Coulomb repulsion ($U = 0.5 - 3eV$), strong crystal field effect ($CF = 1 - 5eV$) and spin-orbit coupling ($\lambda_{SOC}$ = $0.1 - 1eV$) [12], potentially leading to novel quantum phases such as a topological Mott insulator, Weyl semimetal, axion insulator, high-$T_C$ superconductivity, and continuous metal insulator transition (MIT) [3,15] etc. The interplay of competing interactions are controlled inter-alia by the $Ir$-$O$-$Ir$ bond angle and $Ir-O$ bond length, which can be tuned by chemical, physical or surface pressure [14]. A small perturbation in $R$-site or $Ir$-site in $R_2Ir_2O_7$ ($R = Y, Bi$ or rare earth elements) pyrochlore iridates may easily destabilize the ground states.

Experimental studies show that $Ir-O-Ir$ bond angle increases as the $R$-site ionic radius increases resulting in a wider $t_{2g}$ bandwidth leading to MIT [19,20]. Depending on the substituted element, the SOC and U can be tuned using chemical doping at $Ir$-site. For example, lighter element compared to $Ir^{4+}(5d^5)$ would reduce the SOC and enhance $U$ simultaneously. For $Y_2Ir_2O_7$, the magnetic properties are determined by the contribution from $Ir^{4+}$ ion. $Y_2Ir_2O_7$ shows a spin-glass like behaviour or canted ferromagnetic transition at temperature $T \sim 160K$ [25,34]. Chemical doping of isovalent non-magnetic $T^{4+}(3d^0)$ [22] and magnetic $Ru^{4+}(4d^4)$ [21] ions [both have smaller SOC and larger U than $Ir$] individually at magnetic $Ir^{4+}(5d^5)$ site in $Y_2Ir_2O_7$ compounds would lead to enhancement in $Ir-O-Ir$ bond angle and reduction in $Ir-O$ bond length. This produces marginal enhancement of electrical conductivity with large increase in antiferromagnetic correlation. Strikingly, chemical doping of magnetic $Cr^{3+}(3d^3)$ ion at magnetic $Ir^{4+}$ site reduces $Ir-O-Ir$ bond angle and enhances $Ir-O$ bond distance substantially, giving rise to enhancement of orders of magnitude of electrical conductivity and ferromagnetism.

So far as doping at $R$-site is concerned, previous reports on chemical doping of $Ca^{2+}-3p^6$ at $Y^{3+}-4p^6$ site in $Y_2Ir_2O_7$ system alter the electron band width of $Ir-t_{2g}$ [30,34] and show enhancement of electrical conductivity along with weakening of antiferromagnetic correlation. On the other hand, introduction of isovalent non-magnetic $Bi^{3+}-6s/6p$ ion at non-magnetic $Y^{3+}$ site in $Y_2Ir_2O_7$ site does not alter the $t_{2g}$ bandwidth and yet show MIT with spin-glass like behaviour, similar to other $Y$-based pyrochlores like $Y_2-xBi_xRu_2O_7$ [28] and $Bi_{2-x}Y_xRu_2O_7$ compounds [26]. Very recently, a gapped out Weyl-semimetal phase has also been reported in the $Bi$ doped $Y_2Ir_2O_7$ nanoscale system [32,39]. Despite several reports on chemical doping at non-magnetic $R = Y$ site, a thorough analysis of electronic structural parameters, which is necessary to develop an understanding of transport and magnetic properties in these system, is presently lacking.

In the present work, we have studied the effect of electronic structure parameters on the magnetic and electrical transport properties of $Y_{2-x}Bi_xIr_2O_7$ ($x = 0.0, 0.1, 0.2, 0.3$) compounds using XRD, FE-SEM, XPS, Raman spectroscopy, electrical transport in applied magnetic field and dc magnetization measurements. We show that isovalent doping of non-magnetic $Bi^{3+}$ ion at non-magnetic $Y^{3+}$ site in $Y_2Ir_2O_7$ site alters the electronic parameters such as lattice constant, bond angle, bond length and charge states of $Ir$ leading to orders of magnitude enhancement of electrical conductivity and antiferromagnetic correlations compared to the undoped $Y_2Ir_2O_7$ compound.

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cause their matching ionic radii $\text{Bi}^{3+}$ in XRD peak position is not observed. It is expected to be

$\alpha$ with Cu K$\alpha$ (XRD) using a PANalytical XPertPRO diffractometer. The actual composition of the samples were determined using energy dispersive x-ray spectrometry (EDX) with the help of field emission scanning electron microscope (FE-SEM) [JSM-7100F, JEOL]. Electrical transport properties were measured by conventional four probe technique. The magnetization measurements were performed in a Quantum design physical property measurement system (PPMS). The electronic structure was characterized by the X-ray photoelectron spectroscopy (XPS) using a PHI 5000 Versa Probe II system.

II. EXPERIMENTAL METHODS

The samples ($Y_{2-x}Bi_xIr_2O_7$, $y = 0, 0.1, 0.2, 0.3$; and $Y_xIr_2(1-x)Cr_xO_7$, $x = 0, 0.05, 0.1, 0.2$) were prepared using the method described elsewhere $^{12,13,24,25}$. The crystal structure was analyzed by powder X-ray diffraction (XRD) using a PANalytical XPertPRO diffractometer with Cu K$\alpha$ radiation ($\lambda = 1.54$ Å) at room temperature. The actual composition of the samples were determined using energy dispersive x-ray spectrometry (EDX) with the help of field emission scanning electron microscope (FE-SEM) [JSM-7100F, JEOL]. Electrical transport properties were measured by conventional four probe technique. The magnetization measurements were performed in a Quantum design physical property measurement system (PPMS). The electronic structure was characterized by the X-ray photoelectron spectroscopy (XPS) using a PHI 5000 Versa Probe II system.

III. RESULTS AND DISCUSSION

![FIG. 1. Powder XRD profile along with Rietveld refinement taking pyrochlore cubic structure have been shown for $Y_{2-x}Bi_xIr_2O_7$. Inset shows the Bi doping concentration dependent goodness of fit value obtained from Rietveld fitting.](image)

Figure 1 shows powder X-ray diffraction (XRD) pattern for $Y_{2-x}Bi_xIr_2O_7$ series with $x = 0.0, 0.1, 0.2$ and $0.3$. The XRD spectra with diffraction peaks for the undoped compound ($x = 0.0$) consistent with the reported study$^{23}$. With substitution of Bi at Y-site, major change in XRD peak position is not observed. It is expected because their matching ionic radii $[Bi^{3+} = 1.17\text{Å}$ and $Y^{3+} = 1.019\text{Å}]^{39}$ Indeed, XRD spectra does not change notably with doping concentration $x$ except some impurities such as $Bi_2O_3, IrO_2, Y_2O_3$ and $Ir$, which is present minimally ($\leq 3\%$) in the series. The XRD spectra have been analyzed by Rietveld refinement program. The refinement results show all the compounds exhibit a nearly pure pyrochlore phase of cubic Fd$\bar{3}m$ (227) except for few impurity phases shown in Fig. 1 consistent with what others have been reported$^{26,10}$ These impurities are either diamagnetic or paramagnetic in nature, hence have negligible contribution to the physical properties. Statistical goodness of fit defined as $F^2 = [R_{wp}/R_{exp}]^2$, where, $R_{exp}$ is the observed weighed profile factor and $R_{wp}$ the expected weighed profile factor in Rietveld refinement. $^{10}$

The goodness of fit as a function of Bi doping concentration ($x$) shown in inset of Fig. 1 suggest the quality of fitting. Interestingly, Fig. 3 shows that the lattice parameters increases with increasing Bi doping concentration ($x$). It is expected that smaller $Y^{3+}$ ($1.019\text{Å}$) were replaced by larger $Bi^{3+}$ ($1.17\text{Å}$) ion in $Y_xIr_2O_7$ gradually. The enhancement of lattice constant may be associated to a remarkable increase in Y-site ionic size. The representative field emission scanning electron microscope (FE-SEM) micrograph for two members of this present series i.e. $x = 0.0$ and $0.3$ are shown in Fig. 2a,b. The SEM micrograph of parent sample [Fig. 2a] reveals nearly uniform distribution of closely packed grains of different shapes of particles with average particle size $1\mu$m. On the other hand, Fig. 2b shows faceted formation of particles. Inset of Fig. 2b displays the faceted single crystal wires with typical length ranging between 1-50$\mu$m, loosely attached to the surface of polycrystalline sample of $x = 0.3$. Such formation of faceted single crystal possibly due to self-flux growth involving $Bi_2O_3$ as a flux. $^{11}$ The chemical composition of desired element in polycrys-
Bi parameter as a function of Ir give rise to perfect cubic field for octahedron about (0, 0, 0) for the value of x = 0.3125 respectively. Pyrochlore crystal structure show perfect positional parameter) and 8b(0.375, 0.375, 0.375) sites, rally reside at the 48f(r, 0.125, 0.125, where r termed as nates:

\[ R = \frac{Y}{2} \]

the four non-equivalent ions reside at following coordi-
tive x-ray spectrometry (EDX) taken at a large area of
the sample [shown in inset of Fig. 2c,d], show the average
expected presence of Ir, Bi, Y and O in nearly stoichiometric ratio as shown in Fig. 2c,d. It can be noticed that
the Ir/Y ratio is \( \sim 0.84 \) in the \( x = 0.0 \) sample and the
Ir/(Y+Bi) is \( \sim 0.95 \) in the \( x = 0.3 \) sample, suggest that
those samples are Ir-deficient. The low Ir/Y ratio for
undoped compound is not surprising due to volatile na-
ture of \( IrO_2 \). The higher value of Ir/(Y+Bi) ratio for \( x = 0.3 \) sample as compared to \( x = 0.0 \) might be associated
to the high volatile nature of Bi and stability of \( Ir_2O_7 \) in
\( Y_{2-x}Bi_xIr_2O_7 \) series.

In ideal pyrochlore iridates with formula \( R_2Ir_2O_7 \),
the four non-equivalent ions reside at following coordinates: \( R \) at 16d site (0.5, 0.5, 0.5), \( Ir \) at 16c (0, 0, 0) site,
two types of oxygen, \( O \) and \( O' \) ions coordinated tetrahe-
drally reside at the 48f(r, 0.125, 0.125, where r termed as
positional parameter) and 8b(0.375, 0.375, 0.375) sites,
respectively. Pyrochlore crystal structure show perfect
eightahedron about (0, 0, 0) for the value of \( x = 0.3125 \)
give rise to perfect cubic field for \( Ir \) cation in this \( Ir-O_6 \)
eightahedra. Figure 3b reveals the adjustable positional
parameter as a function of \( Bi \) doping concentration \( x \).

The estimated value of positional parameter for parent
compound turns out to be 0.355, greater than the ideal
value, suggests disordered and compressed \( Ir - O_6 \)
eightahedra. For \( Y_{2-x}Bi_xIr_2O_7 \) series, positional parameter
decreases with increase of the \( Bi \) content, lead towards
ideal \( IrO_6 \) eightahedra with reduced crystal field. The
doping dependence of \( Ir - O \) bond distance and \( Ir - O - Ir \)
bond angle are shown in Fig. 3c,d, respectively. The bond
length decreases while bond angle increases with increasing
concentration of \( Bi \) in \( Y_{2-x}Bi_xIr_2O_7 \) series. This is
due to the introduction of heavy \( Bi^{3+} \) atom with greater
ionic size than \( Y^{3+} \). This implies reduction of distortion in
the \( Ir - O_6 \) eightahedra and enhancement in
the hybridization of \( Y(4p)/Bi(6s \& 6p) \) with \( O(2p) \)
and \( Ir(5d) \) states. The enhancement in \( Ir - O - Ir \) bond
angle and reduction in \( Ir - O \) bond length can be un-
derstood by Fig. 4a,b. Cartoon shows the arrangement
of atoms in the undoped compound where the coordina-
tion environments of each oxygen atom is associated
with two \( Ir \) and two \( Y \) cations to make a distorted eightahedra
along c-axis in the unit cell [Fig. 4b]. When \( Bi^{3+} \)
is introduced, it pushes the oxygen atom further away
from the \( R \)-site along the perpendicular bisector of the
\( Ir - O - Ir \) triangle, thus increasing the \( Ir - O - Ir \) bond
angle [Fig. 4b].

The temperature dependence of the magnetic susceptibility \( \chi = M/H \) for \( Y_{2-x}Bi_xIr_2O_7 \) (\( x = 0.0, 0.1, 0.2, 0.3 \) series measured at applied magnetic field 1kOe follow-
ing the zero field cooled (ZFC) and field cooled (FC)
protocol. For un-doped compound, it can be noticed that

![Image 319x549 to 560x740](image-url)

**FIG. 3.** Bi doping content depended (a) Lattice parameter,
(b) positional parameters \( r \) of \( O \) atom, (c) \( Ir - O \) bond length
(d) \( Ir - O - Ir \) bond angle for the \( Y_{2-x}Bi_xIr_2O_7 \) series.

![Image 56x421 to 297x510](image-url)

**FIG. 4.** Oxygen coordination environment showing the effect
of \( R \) cation size on the local structure of (a) small \( Y \) cation
in \( R_2Ir_2O_7 \) system, (b) larger \( Y \) cation in \( Y_{2-x}Bi_xIr_2O_7 \).

![Image 56x568 to 297x740](image-url)

**FIG. 5.** (a) Field cooled (solid continuous line) and zero field
cooled (dashed line) magnetic susceptibilities as a function of
temperature for \( Y_{2-x}Bi_xIr_2O_7 \) (\( x = 0.0, 0.1, 0.2, 0.3 \) series;
inset shows \( Bi \) doping concentration dependent magnetic ir-
rresible \( T_{Ir}\). (b) The inverse of magnetic sus-
ceptibility \( \chi^{-1} = H/M \) as a function of temperature. Red
solid line associated to the the fit using the Curie-Weiss (CW)
law. The variation of (c) Curie-Weiss temperature \( \theta_{CW} \), and
(d) effective magnetic moment \( \mu_{eff} \) with \( Bi \) doping content \( x \).
interaction as discussed earlier [Fig. 6a,c,d]. For parent compound (x = 0.0), the Ir – O – Ir bond angle is 121° [very close to ideal value $\theta_{\text{ideal}}$], much larger than 90° promoting the super exchange interaction. With Bi doping $\theta_{\text{irr}}$ increases but the actual ordering temperature decreases. This suggests enhancement of frustration parameter [$f = \theta_{\text{eff}}/\theta_{\text{irr}}$ with Bi doping. The effective magnetic moment $\mu_{\text{eff}}$ for all the samples plotted as a function of Bi doping concentration shown in Fig. 6d). The estimated value of $\mu_{\text{eff}}$ for undoped compound is 2.0 $\mu_B$/f.u. which is larger than the expected Hund’s rule value of 1.73 $\mu_B$/f.u. for $S = 1/2$. Similar inconsistency [i.e. obtained experimental value of $\mu_{\text{eff}}$ being larger than expected theoretical value of a spin 1/2] has also been reported.

Such disagreement with Hund’s rule value is not unusual in presence of crystal field effect and strong spin-orbit coupling. It can be noticed that $\mu_{\text{eff}}$ decreases as non-magnetic Bi content increases shown in Fig. 6b).

The magnetic field (H) dependence isothermal magnetization (M) for two representative samples x = 0.0, 0.3 of the Y$_2$-Bi$_x$Ir$_2$O$_7$ series measured at temperature 2K is shown in Fig. 6 The M-H data show non-linear trends with no sign of saturation up to 10T. The coercive field $H_C$, saturation magnetization $M_s$ and remanent magnetization $M_R$ show considerable reduction compared to the un-doped sample. It is obvious that Y$_2$-Bi$_x$Ir$_2$O$_7$ series have tendency towards an increased AFM correlation, supports the enhanced negative $\theta_{\text{CW}}$ with increased Bi doping content. A narrower magnetic hysteresis loops show considerable reduction compared to x = 0.3 sample can be seen at low magnetic field [inset of Fig. 6], suggesting very weak FM component. This result is possibly due to the canted antiferromagnetic spin coupling instead of ferromagnetic correlation. The coexistence of very weak ferromagnetic component on the large AFM background suggests that only a partial fraction of short-range ordered spins freeze at low temperature into random direction. This behaviour might be attributed to spin-glass-like transition, possibly arising due to local structural disorder and magnetic frustration. This behaviour weakens with introduction of Bi content i.e., magnetically ordered state in undoped compound reduces as Bi doping content increases. To conclude, in Y$_2$-Bi$_x$Ir$_2$O$_7$, the magnetically ordered state associated to $\theta_{\text{CW}}$ magnetic ions remains same but the paramagnetic volume fraction get larger and larger.

In order to further investigate the possibility of spin-glass-like behaviour in Bi doped Y$_2$Ir$_2$O$_7$ pyrochlore iridates, we have measured the isothermal remanent magnetization. For this measurement, the samples are ZFC from room temperature to 5K. A dc magnetic field of 1kOe is applied after stabilizing the temperature and waiting upto 10$^5$s, and magnetization is measured as a
FIG. 7. (a) Time dependence of the normalized isothermal remanent magnetization measured at temperature 5K with waited time $t_w = 10^3$ s for the two representative samples $x = 0.0, 0.3$ of the $Y_{2-x}Bi_xIr_2O_7$ series. Solid red line show corresponding fit of data using Eq. 1. (b) Semi-log plot of normalized magnetization as a function of time. Dashed red line are due to the fit using Eq. 1. Solid green line shows linear portion.

function of elapsed time $t$. Figure 7(a) shows the time dependence of ZFC isothermal remanent magnetization normalized with magnetization value $M(t = 0)$ for two representative samples $x = 0.0, 0.3$ of the $Y_{2-x}Bi_xIr_2O_7$ series. For $x = 0.0$ sample, $M(t)/M(0)$ increases with time without any sign of saturation, although $x = 0.3$ sample is trying to achieve saturation at higher time scale. We have analysed the normalized magnetic relaxation data with fitting of stretched exponential function

$$
\frac{M(t)}{M(t = 0)} = \exp \left[ \frac{t}{\tau} \right]^{\gamma}
$$

where $\gamma$ is stretching exponent and $\tau$ is the characteristic relaxation time. The value of $\gamma$ give the information about the nature of energy barriers involved in magnetic relaxation. System exhibiting a single energy barrier should give an exponential magnetic relaxation for the value of $\gamma \geq 1$. In real system, several energy barriers involved in magnetic relaxation, lead to a distribution of relaxation times. The solid red lines shown in Fig. 7 are due to fitting of stretched exponential Eq. 1 giving the value of $\gamma = 0.37$ ($x = 0.0$) and 0.4 ($x = 0.3$), respectively. Simultaneously, it can be noticed that $Bi$ doping decreases the relaxation time $\tau$ $[x = 0.3, \tau \sim 2.4 \times 10^7]$ almost by two order as compared to un-doped compound $[x = 0.0, \tau \sim 8.5 \times 10^9]$. The estimated values of $\gamma$ and $\tau$ are in good agreement with the values observed for spin-glass system. This clearly suggest that $Bi$ doping relaxes the system at a faster rate. Figure 7(b) displays time dependent semi-logarithmic plot of normalized magnetic relaxation data. Parent compound shows continuous increase of magnetization with time. On the other hand, sample $x = 0.3$ enters in a regime of saturation at higher time scale (after $\tau_2$). In this regime, the magnetization change tends to zero for $t \gg \tau_2$ and for $t \ll \tau_1$, the magnetization varies linearly with time, consistent with a distribution function of finite width. Therefore, it can be concluded that $Y_{2-x}Bi_xIr_2O_7$ series looks like glassy mixed phase.

FIG. 8. (a) Log-log plot of resistivity as a function of temperature for $Y_{2-x}Bi_xIr_2O_7$ series. The solid black line represents the theoretical fit due to power law. (b) First temperature derivative of the resistivity $d\rho/dT$ as a function of temperature; inset show enlarged view for samples $x = 0.1, 0.2, 0.3$.

FIG. 9. Magnetoresistance as function of applied magnetic field for $Y_{2-x}Bi_xIr_2O_7$ series measured at temperature 2K. Inset shows quadratic field dependence of MR.
Figure 8k shows the temperature dependence of the electrical resistivity of $Y_{2-x}Bi_xIr_2O_7$ series. The $x = 0.0$ sample is known to show an insulating behaviour in the whole temperature range where the $\rho(T)$ behaviour follows a power law dependence. The insulating behaviour diminishes with $Bi$ doping shown in Fig. 8k. For doping level $x = 0.1$, insulator like temperature dependence is observed, while for $x = 0.2$ and 0.3, we find much lower resistivity with minima at temperatures $\sim 140$ K, 130 K, respectively, which is consistent with previous reports. Figure 8b shows temperature dependent derivative of the resistivity $d\rho/dT$. Inset of Fig. 8b demonstrate the change in slope from positive $[d\rho/dT > 0$, conventional metal] to negative $[d\rho/dT < 0$, insulator] for the samples $x = 0.2$ and 0.3. Given that another member of this pyrochlore iridate family, i.e., $Bi_2Ir_2O_7$ shows a metallic state with strongly enhanced paramagnetism, the $\rho$ exponent & production mechanism in parent sample follows the following relation in lattice constant for small doping content, suggests these chemical substitution ($Co$, $Ca$ in $Bi_2Ir_2O_7$) shows a metallic state with strongly enhanced paramagnetism as well as contraction in the fitting temperature range $\sim 140$ K, 130 K, respectively, which is consistent with previous reports. On the other hand, chemical doping of $Co^{3+}$ and $Ca^{2+}$ separately at $Bi$-site in $Bi_2Ir_2O_7$ compound shows MIT with weakening of AFM interaction. These chemical substitution ($Co$, $Ca$ in $Bi_2Ir_2O_7$) try to achieve MIT with weak AFM correlation, opposite to what $Bi$ doping does for $Y_2Ir_2O_7$. Moreover, very recently $Bi$ doped $Eu_2Ir_2O_7$ show anomalous contraction in lattice constant for small doping content, suggests proximity to the Weyl semimetal phase. As the conduction mechanism in parent sample follows the following power law model, $\rho = \rho_0T^{-n}$, where $n$ is the power law exponent & $\rho_0$ is the prefactor, respectively, the $\rho(T)$ data are analyzed by fitting to the power law in the temperature range $10$-$70K$ ($x = 0.0$), 10-$55K$ ($x = 0.1$), 10$-40K$ ($x = 0.2$), 10-$35K$ ($x = 0.3$) shown in Fig. 8b. The fitting parameters are estimated to be $n \sim 2.97$ ($x = 0.0$), 1.6 ($x = 0.1$), 0.6 ($x = 0.2$), 0.1 ($x = 0.3$), samples, respectively. The alteration in value of power exponent $n$ as well as contraction in the fitting temperature range likely due to fast variation in $\rho(T)$.

The MIT state in $Y_{2-x}Bi_xIr_2O_7$ series is of general interest. While replacement of $Y^{3+}$ with $Ca^{2+}$ leads to hole doping, which in turn, gives rise to a finite density of states near the Fermi level, the introduction of $Bi$ in $Y_2Ir_2O_7$ system does not create holes but fills up the 5d orbital. The greater ionic radius of $Bi^{3+}$ (1.17 Å) compared to $Y^{3+}$ (1.01 Å) introduces disorder into the compound by spatially deforming the cell volume. Substitution of $Bi^{3+}$ ions enhances the hybridization between the $Bi\ 6s/6p$ orbital with the $Ir\ 5d$ orbital. The energy of this hybridization is much larger than the SOC and Coulomb correlation, which makes the $Ir\ 5d$ bandwidth wider and drives the system into a metallic state. However, another fact that may push $Y_{2-x}Bi_xIr_2O_7$ to MIT state is an enhancement in the $Ir - O - Ir$ bond angle as $Bi$ doping content increases. It is known that for strong hybridization of $p$ orbital of oxygen with $Ir^{4+}\ (5d^5)$ orbital, $Ir - O - Ir$ angle should be $180^0$ in a $\Pi$ type interaction. Because of the enlarged nature of $Ir - 5d$ orbitals, the mixing of $O(2p) - Ir(5d)$ is sufficient favours the interatomic exchange interaction. The reported $Ir - O - Ir$ bond angle is $116^0$ in $Y_2Ir_2O_7$ system, much greater than $90^0$ supports the $Ir - O - Ir$ antiferromagnetic superexchange interaction, leading towards a noncollinear and strong magnetic frustration. On the other hand, the $Ir - O - Ir$ angle is $131.4^0$ in metallic $Bi_2Ir_2O_7$. Thus, it could be argued that the reason for improved conduction in $Bi$ doped $Y_2Ir_2O_7$ compounds, possibly due to enhancement in $Ir - O - Ir$ bond angle as shown in Fig. 8a.

Fig. 9 shows the magnetoresistance (MR) as a function of magnetic field measured at temperature 2K. MR is defined as $[MR = \rho(H) - \rho(0)]/\rho(0) \times 100]$. The undoped compound ($x = 0.0$) is known to show positive MR at low magnetic field accompanied by negative MR with quadratic field dependence at higher magnetic field. The negative MR is progressively suppressed with $Bi$ doping shown in Fig. 9, although, quadratic field dependence is still observed shown in inset of Fig. 9. The MR behaviour produced by quantum interference in presence of strong SOC is described by two time scales. (I) spin-flip time $\tau_{so}$, and (II) the dephasing time $\tau_{\phi}$. When $\tau_{\phi} \gg \tau_{so}$, i.e. non-magnetic impurity scattering is dominant, destructive quantum interference between time reversed trajectories is obtained, leading to weak antilocalization and a positive MR. In $\tau_{\phi} < \tau_{so}$ regime, i.e. when SOC is weak, the quantum interference is always in-phase and constructive giving rise to negative MR with increasing magnetic field (Weak localization). The weakening of negative MR with $Bi$ doping implies enhancement of spin-orbit coupling due to the replacement of $Y^{3+}$ with non-magnetic heavier $Bi^{3+}$.

Figure 10 shows de-convoluted spectra of $Ir\ 4f$ core-level XPS of two representative sample $x = 0.0, 0.3$ of $Y_{2-x}Bi_xIr_2O_7$ series using asymmetric Gauss-Lorentz sum function. XPS peaks are labeled following the protocol reported elsewhere. For $Ir^{4+}$, $4f_7/2$ and $4f_5/2$ electronic states arise at binding energy around $62eV$ and $65eV$ due to spin-orbit coupling, respectively, which are represented by blue solid line and blue dashed line in Fig. 10. Similarly, higher oxidation state $Ir^{5+}$ centered at $63.7eV$ and $67eV$ shown by green solid line and green dashed line, respectively in Fig 10a for $4f_7/2$ and $4f_5/2$. Fitted result show very small contribution from the $Ir^{3+}$ oxidation state along with major contribution from the $Ir^{4+}$ charge state for $x = 0.0$ sample, consistent with previous reports. For $Bi$ doped compounds, the contribution from $Ir^{3+}$ is minimally increased. It suggest the marginal increase in $Ir$ oxidation state, i.e. $Ir^{4+}$ and $Ir^{4+}2^+$, as $Bi$ doping content increases shown in Fig. 10d. Therefore, it seems that replacement of $Y^{3+}$ by $Bi^{3+}$ does not support the formation of higher oxidation states. However, it can create anion vacancies at $O^-$ sites which is favorable due to presence of polarizable $Bi^{3+}$ cation at $Y^{3+}$ site. Figure 10 shows $Y3d$ XPS for $x = 0.0, 0.1, 0.2, 0.3$ samples. Variation in the $Bi - 4f$ and $Y - 3d$ XPS spectra with different doping concentration of $Bi$ can also be seen. The $Y - 3d$
enhancement in the peak area ratio of O assigned to oxygen lattice of YBiO. Fig. 10b. The peaks located at binding energies 529 eV and 529 eV are consistent with the Y3+ and Bi4+ XPS for x = 0.0, 0.1, 0.2, 0.3 compounds. (d) Intensity ratio I5+/I4+ I5+/I4+ and asymmetry factor (shown in inset) as a function of Bi doping content (x), where I = Ir.

shows a single feature at 156.4 eV and 158.3 eV, suggest that only Y3+ is present in the x = 0.0 sample. On the other hand, we observe a superposition of the Y − 3d and Bi − 4f XPS peaks. It is clear that Y − 3d peaks exhibit the Bi − 4f peak due to overlapping of energy ranges. The details about XPS of Bi doped Y2O3 is given elsewhere. In further support of mixed oxidation state, the O 1s XPS spectra for x = 0.0, 0.3 compounds are shown in Fig. 10b. The peaks located at binding energies 529 eV and 531 eV are attributed as lower O(L) and higher O(H) binding energy peaks, respectively. The O(L) is assigned to oxygen lattice of Y2−x Bix Ir2O7 series while O(H) is related to oxygen vacancies or defects. The enhancement in the peak area ratio of O(L)/O(L) against Bi doping content suggests the enhancement in oxygen vacancies in the compounds with increased Bi doping. We have estimated asymmetric factor in Ir 4f XPS following the protocol report elsewhere and plotted as a function of Bi doping content (x) shown in inset of Fig. 10. It is obvious that less conducting parent sample exhibit less asymmetric compared to high conducting x = 0.1, 0.2, 0.3 samples. Asymmetry in Ir 4f line shapes can be attributed to the 5d conduction electron screening, which could also explain the enhanced conductivity of the doped samples.

To further explore structural change and the possible cause behind the huge reduction in electrical resistivity in Bi doped samples as compared to parent compound, Raman spectroscopy has been carried out. Figure 11 shows Raman spectra recorded at room temperature for x = 0.0, 0.3 samples. An ideal cubic pyrochlore iridate with formula R2Ir2O6O′, space group Fd3m should have six Raman active fundamental modes distributed among A1g + Eg + 4T2g modes, involving only vibrations of oxygen at both 48f and 86 sites. Table I show indexed modes with their respective wave numbers. The four peaks named as T2g, T2g, T2g, and T2g are Raman active while the peak named as T1 has been reported as second order scattering for pyrochlore oxides. The most characteristic features of Ir-pyrochlore spectra are a sharp mode at ~ 391 cm−1, and ~ 523 cm−1 which includes contributions from the Eg mode and A1g mode, respectively. It have been shown that intermediate vibrational modes E2g-T2g and A1g-T2g arise due to vibrations of Ir − O and R − O′ bond. Here, A1g mode is related to the positional parameter, directly affecting the R − O′ bond environment. For x = 0.3 sample, Eg-T2g vibrational mode shift towards lower wave number, while A1g-T2g modes towards higher wave number as compared to parent compound. This feature are arising due to enhancement in hybridization between Y(4p)/Bi(6s), O − 2p and Ir − 5d orbitals suggest reduction in Ir − O bonds consistent with XRD shown in Fig. 3 and enhancement in R − O′ bonds. In this process t2g bandwidth increases as the R-site ionic radius increases lead to enhanced electrical conductivity.

The plausible scenario for the MIT in the Y2−x Bix Ir2O7 series compounds is related to the modification in structural parameters, arising due to the

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**FIG. 10.** (a) deconvoluted Ir 4f peaks for x = 0.0, 0.3 samples, (b) deconvoluted O 1s peaks of the x = 0.0, 0.3 compounds. (c) Y 3d and Bi 4f XPS for x = 0.0, 0.1, 0.2, 0.3 compounds, (d) Intensity ratio I5+/I4+ I5+/I4+ and asymmetry factor (shown in inset) as a function of Bi doping content (x), where I = Ir.

**FIG. 11.** Intensity normalized Raman spectra of two representative samples x = 0.0, 0.3 of Y2−x Bix Ir2O7 series measured at room temperature in the spectral range 200-800 cm−1.

**TABLE I.** Indexed Raman peaks with their respective wavenumbers

<table>
<thead>
<tr>
<th>Modes</th>
<th>T2g</th>
<th>T2g</th>
<th>T2g</th>
<th>E2g</th>
<th>A1g</th>
<th>T1</th>
</tr>
</thead>
<tbody>
<tr>
<td>Wavenumber</td>
<td>305</td>
<td>550</td>
<td>550</td>
<td>630</td>
<td>391</td>
<td>523</td>
</tr>
</tbody>
</table>
isovalent Bi substitution at the Y-site as distinct from the previous studies which rarely focus on the relation between structural parameters and the magnetic and the transport properties.

IV. CONCLUSION

We have investigated the structural, magnetic, and electrical transport properties of the pyrochlore iridates \( Y_2-xBixIr_2O_7 \). The replacement of \( Y^{3+} \) with \( Bix^{3+} \) stabilizes the antiferromagnetic correlation and enhances electronic conductivity. The XRD analysis shows \( Ir - O - Ir \) bond angle increases and \( Ir - O \) bond length decreases as distortion in \( Ir - O_6 \) octahedra is reduced against increasing \( Bix^{3+} \) doping content. The X-ray photoemission spectroscopy measurements suggest marginal enhancement in \( Ir \) oxidation states ranging from \( Ir^{4+} \) to \( Ir^{3+} \) with Bi doping, promoting the anion vacancies at O’ site. The enhancement in electrical conductivity with \( Bix^{3+} \) is likely a consequence of hybridization between the \( Y(4p)/Bi(6s) \), \( O - 2p \) and \( Ir - 5d \) orbitals. Raman spectroscopy shows contraction in \( Ir - O \) bonds [consistent with XRD results] and elongation in \( R - O' \) bonds as disorder and phononic oscillation are reduced by Bi doping, leading to orders of magnitude enhancement of electrical conductivity along with MIT. On the other hand, enhancement in antiferromagnetic correlation can be explained in term of increased \( Ir - O - Ir \) bond angle against Bi doping. Bifurcation between \( \chi_{ZFC} \) and \( \chi_{FC} \) at higher temperature with hysteretic isothermal magnetization at low magnetic field might be associated to spin-glass-like transition rather than long-range ordering, as confirmed by magnetic relaxation measurements. This is attributed to the coexistence of antiferromagnetic and ferromagnetic correlations.

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